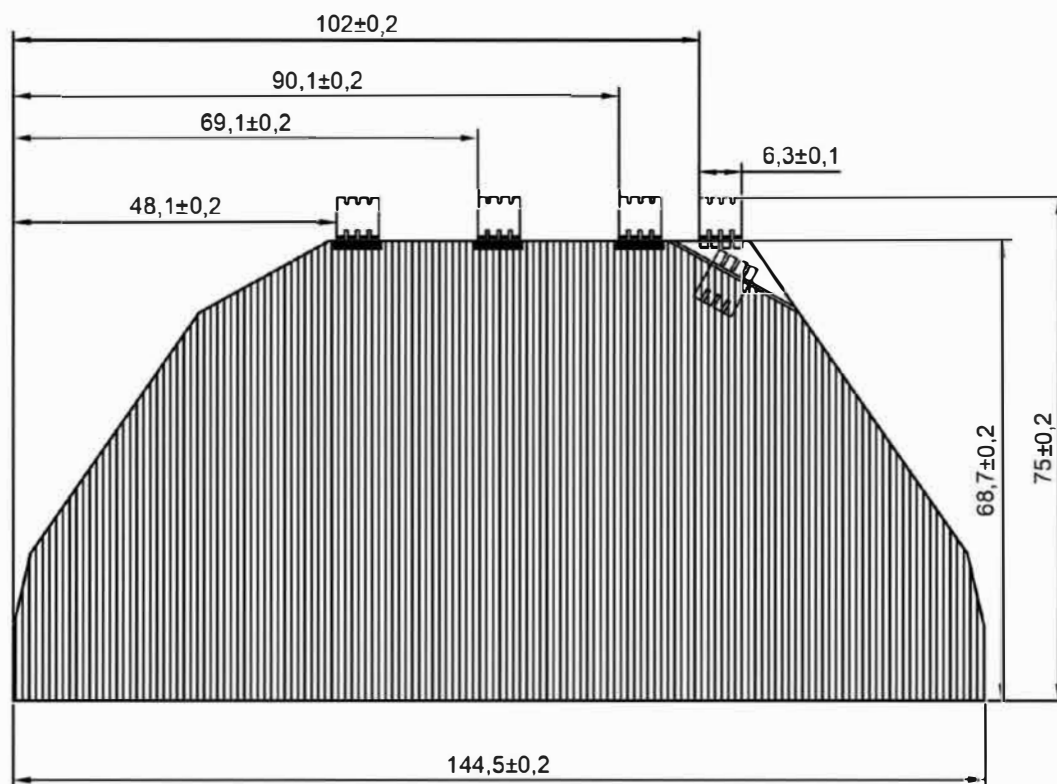
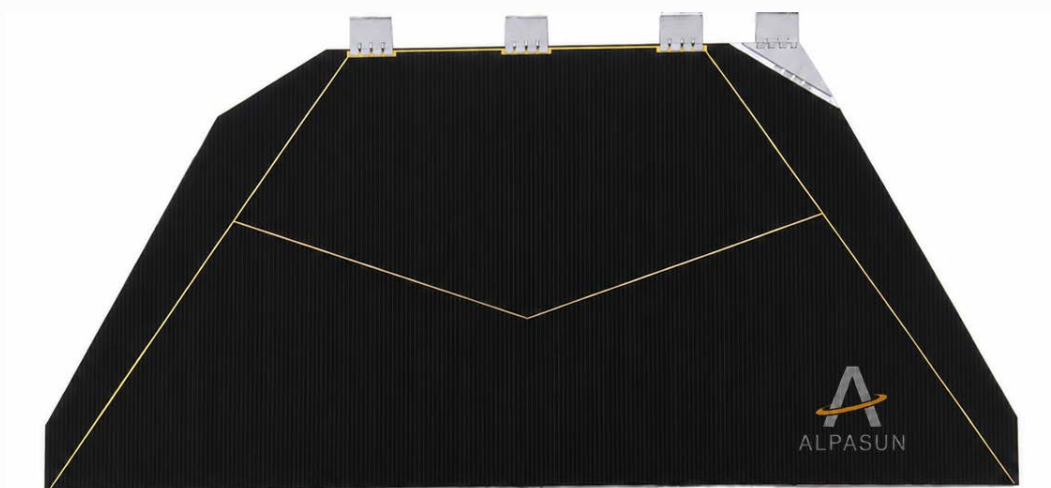


Triple Junction GaAs Solar Cell Assembly **(144.5mm×68.7mm)**



Contact information

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Features

- Fabricated on a germanium substrate using MOCVD epitaxial growth, semiconductor device processing and radiation-resistant packaging;
- GaInP/GaAs/Ge on Ge substrate triple junction solar cell assembly;
- Efficiency $\geq 30.5\%$ (25 °C, AM0 1353 W/m²);
- Reinforced with radiation-resistant coverglass, external Si diode protection, and interconnect soldering of Kovar silver-plated components, providing excellent durability in the space environment.

Design and Mechanical Data

Base Material	GaInP/GaAs/Ge on Ge substrate
Contact Metallization Thickness	4~5 μ m(Ag)
AR-coating	TiO _x /Al ₂ O ₃
Dimensions	(144.5 $\pm$ 0.2 mm) $\times$ (68.7 $\pm$ 0.2 mm)
Cell Area	80.00cm ²
Areal density	≤ 170 mg/cm ²
Thickness	0.47 $\pm$ 0.05mm
Coverglass thickness	120 $\pm$ 15 μ m
Interconnects	Kovar, silver coated
Interconnectorthickness	25 $\pm$ 4 μ m
Pull Test	≥ 1.0 N/mm ² with 25 μ m kovar/Ag stripes by pulling at 45°
Bypass protection	External Si diode

Electrical Data

Data	BOL	1.0E+14	2.0E+14	5.0E+14	1.0E+15
Open Circuit V _{oc} (mV)	2750	2602	2600	2557	2481
Short Circuit I _{sc} (mA)	1406.3	1403.6	1403.6	1401.0	1377.1
V _{mp} @Max. Power (mV)	2430	2304	2299	2270	2187
I _{mp} @Max. Power (mA)	1379.7	1377.1	1377.1	1377.1	1347.9
Fill Factor FF (%)	85	85	85	84	85
Efficiency (%)	30.5	29	29	28	26

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Bypass Diode

Forward Voltage V_F	$\leq 1.0V$ (620mA, $T=25^{\circ}C$)
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Reverse Current I_R	$\leq 25\mu A/mm^2$ (4.0V, $T=25^{\circ}C$)
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Operation Temperature	$-180^{\circ}C$ to $+150^{\circ}C$
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Temperature Gradients

DATA	BOL	1.0E+14	2.0E+14	5.0E+14	1.0E+15
Voltage @max. power (mV/ $^{\circ}C$)	-5.2	-5.4	-5.5	-5.6	-5.8
Current @max. power ($\mu A/cm^2/^{\circ}C$)	6.0	6.2	6.3	6.4	6.5

Absorptivity

Absorptivity	≤ 0.92
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Emissivity	0.84 ± 0.03
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Customization, Handling and Support.

- Product dimensions, configurations and photovoltaic efficiencies can be customized to meet specific customer requirements, subject to technical evaluation.
- This product is fragile, handle with care during transportation, storage, installation and use.
- If a product-related quality issue occurs, we will provide timely technical support, investigate the issue and work with the customer toward an effective resolution.

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